

Linear Systems Ultra Low Leakage Low Drift Monolithic Dual JFET

The LS844 is a high-performance monolithic dual JFET featuring extremely low noise, tight offset voltage and low drift over temperature specifications, and is targeted for use in a wide range of precision instrumentation applications. The LS844 features a 5-mV offset and 10- $\mu\text{V}/^\circ\text{C}$ drift.

The 8 Pin P-DIP and 8 Pin SOIC provide ease of manufacturing, and the symmetrical pinout prevents improper orientation.

(See Packaging Information).

LS844 Applications:

- Wideband Differential Amps
- High-Speed, Temp-Compensated Single-Ended Input Amps
- High-Speed Comparators
- Impedance Converters and vibrations detectors.

FEATURES

LOW DRIFT	$ V_{GS1-2}/T \leq 10\mu\text{V}/^\circ\text{C}$	
LOW LEAKAGE	$I_G = 15\text{pA TYP.}$	
LOW NOISE	$e_n = 3\text{nV}/\sqrt{\text{Hz}}$ TYP.	
LOW OFFSET VOLTAGE	$ V_{GS1-2} \leq 5\text{mV}$	
ABSOLUTE MAXIMUM RATINGS @ 25°C (unless otherwise noted)		
Maximum Temperatures		
Storage Temperature	-65°C to +150°C	
Operating Junction Temperature	+150°C	
Maximum Voltage and Current for Each Transistor – Note 1		
-V _{GSS}	Gate Voltage to Drain or Source	60V
-V _{DSO}	Drain to Source Voltage	60V
-I _{G(f)}	Gate Forward Current	50mA
Maximum Power Dissipation		
Device Dissipation @ Free Air – Total	400mW @ +125°C	

MATCHING CHARACTERISTICS @ 25°C UNLESS OTHERWISE NOTED

SYMBOL	CHARACTERISTICS	VALUE	UNITS	CONDITIONS
$ V_{GS1-2}/T \text{ max.}$	DRIFT VS. TEMPERATURE	10	$\mu\text{V}/^\circ\text{C}$	$V_{DG}=10\text{V}, I_D=500\mu\text{A}$ $T_A=-55^\circ\text{C}$ to $+125^\circ\text{C}$
$ V_{GS1-2} \text{ max.}$	OFFSET VOLTAGE	5	mV	$V_{DG}=10\text{V}, I_D=500\mu\text{A}$

ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

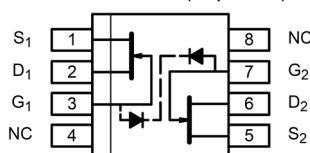
SYMBOL	CHARACTERISTICS	MIN.	TYP.	MAX.	UNITS	CONDITIONS
BV _{GSS}	Breakdown Voltage	60	--	--	V	$V_{DS} = 0$ $I_D=1\text{nA}$
BV _{GGO}	Gate-To-Gate Breakdown	60	--	--	V	$I_G = 1\text{nA}$ $I_D = 0$ $I_S = 0$
TRANSCONDUCTANCE						
Y _{FSS}	Full Conduction	1500	--	--	μmho	$V_{DG}=15\text{V}$ $V_{GS}=0\text{V}$ $f=1\text{kHz}$
Y _{FS}	Typical Operation	1000	1500	--	μmho	$V_{DG}=15\text{V}$ $I_D=500\mu\text{A}$
$ Y_{FS1-2}/Y_{FS} $	Mismatch	--	0.6	3	%	
DRAIN CURRENT						
I _{DSS}	Full Conduction	1.5	5	15	mA	$V_{DG}=15\text{V}$ $V_{GS}=0\text{V}$
$ I_{DSS1-2}/I_{DSS} $	Mismatch at Full Conduction	--	1	5	%	
GATE VOLTAGE						
V _{GS(off)} or V _p	Pinchoff voltage	1	--	3.5	V	$V_{DS}=15\text{V}$ $I_D=1\text{nA}$
V _{GS(on)}	Operating Range	0.5	--	3.5	V	$V_{DS}=15\text{V}$ $I_D=500\mu\text{A}$
GATE CURRENT						
-I _{Gmax.}	Operating	--	15	50	pA	$V_{DG}=15\text{V}$ $I_D=500\mu\text{A}$
-I _{Gmax.}	High Temperature	--	--	50	nA	$T_A = +125^\circ\text{C}$
-I _{Gmax.}	Reduced V _{DG}	--	5	30	pA	$V_{DG}=3\text{V}$ $I_D=500\mu\text{A}$
-I _{GSSmax.}	At Full Conduction	--	--	100	pA	$V_{DG}=15\text{V}, V_{DS}=0$
OUTPUT CONDUCTANCE						
Y _{OSS}	Full Conduction	--	--	20	μmho	$V_{DG}=15\text{V}$ $V_{GS}=0\text{V}$
Y _{OS}	Operating	--	0.2	2	μmho	$V_{DG}=15\text{V}$ $I_D=500\mu\text{A}$
$ Y_{OS1-2} $	Differential	--	0.02	0.2	μmho	
COMMON MODE REJECTION						
CMR	$-20 \log V_{GS1-2}/V_{DS} $	90	110	--	dB	$\Delta V_{DS} = 10$ to 20V $I_D=500\mu\text{A}$
	$-20 \log V_{GS1-2}/V_{DS} $	--	85	--	dB	$\Delta V_{DS} = 5$ to 10V $I_D=500\mu\text{A}$
NOISE						
NF	Figure	--	--	0.5	dB	$V_{DS}=15\text{V}$ $V_{GS}=0\text{V}$ $R_G=10\text{M}\Omega$ $f=100\text{Hz}$ $\text{NBW}=6\text{Hz}$
e _n	Voltage	--	--	7	nV/ $\sqrt{\text{Hz}}$	$V_{DS}=15\text{V}$ $I_D=500\mu\text{A}$ $f=1\text{kHz}$ $\text{NBW}=1\text{Hz}$
		--	--	11		$V_{DS}=15\text{V}$ $I_D=500\mu\text{A}$ $f=10\text{Hz}$ $\text{NBW}=1\text{Hz}$
CAPACITANCE						
C _{ISS}	Input	--	--	8	pF	$V_{DS}=15\text{V}, I_D=500\mu\text{A}$
C _{RSS}	Reverse Transfer	--	--	3		
C _{DD}	Drain-to-Drain	--	0.5	--		$V_{DG}=15\text{V}, I_D=500\mu\text{A}$

Note 1 – These ratings are limiting values above which the serviceability of any semiconductor may be impaired

Available Packages:

LS844 / LS844 in PDIP & SOIC
LS844 / LS844 available as bare die
Please contact [Micross](http://www.micross.com) for full package and die dimensions

PDIP & SOIC (Top View)



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